

Ba₂NiSi₃: A One-Dimensional Solid-State Metallocene Analog

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Polar intermetallics and Zintl phases of group 14 elements exhibit a rich variety of complex structures and chemical bonding.^{1,2} In this regard, the Zintl concept provides a simple and useful way to rationalize relationships between stoichiometry, crystal structure, and chemical bonding along the border between metals and nonmetals.^{2,3}

Investigations on polar intermetallic trielides and tetrelides pose intriguing questions about their ability to accommodate high negative charges, open-shell electronic structures, and multiple bonding.^{4–7} Recent studies aim to understand structural, chemical, and electronic characteristics of “electron-deficient” Zintl phases that exhibit chemical bonding, wherein normal pictures of singly bonded anionic metalloids is insufficient, and hence implies the presence of multiple bonding. The complex Zintl phases, SrCa₂-In₂Ge and Ca₅In₉Sn₆, are illustrative examples.^{5,6} Their electronic and crystal structure patterns emphasize the need to understand the stabilization of intermetallic π -systems.

A challenge in inorganic chemistry is the synthesis of main group compounds, other than carbon, that exhibit unsaturation or aromaticity.^{7,8} Successful syntheses of molecular cyclogallene,⁷ cyclotrigermenium,^{7c} cyclotrisilene⁸ provide the stimuli to prepare new inorganic unsaturated hydrocarbon analogues among polar intermetallics. It has been reported that aromatic Zintl anions isoelectronic to cyclopropenium, such as [Sn₃]²⁻ and [In₃]⁵⁻ were formulated to exist in the superconducting phase, BaSn₃, and the ternary, Ca₅In₉Sn₆.^{6,9}

The title compound Ba₂NiSi₃ (**1**) was obtained in high yield by reacting stoichiometric amounts of the pure elements (with a slight excess of Ba) at high temperatures under argon using an arc furnace. The compound was initially obtained as a minor phase from our attempts to prepare “BaNiSi₂”. Silver needle-like crystals of **1** obtained from the as-cast melt were found to be air-stable up to 1 day, but reacted strongly with moisture. Subsequently, the compound was prepared in high yield (>95%) from the reaction of stoichiometric amounts of Ba, NiSi, and Si within welded Ta tubes at 900 °C. The lack of an appreciable phase width in Ba₂NiSi₃ is indicated by the relatively invariant lattice parameter and unit cell volumes refined from patterns of a number of nomi-

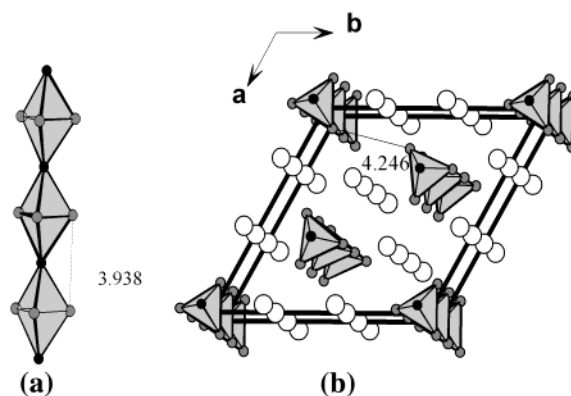


Figure 1. (a) A [NiSi₃]⁴⁻ chain in Ba₂NiSi₃; (b) [001] view of the crystal structure of Ba₂NiSi₃. Atoms are represented as follows: Ba, large light spheres; Ni, small dark spheres; and Si, small gray spheres.

nal compositions. The narrow homogeneity range and the refined chemical composition were confirmed by microprobe/wavelength dispersive (WDS) analysis of bulk and single crystal samples and the observation that single-phase samples were only obtained from reactions with nominal stoichiometry of Ba₂NiSi₃. As a general precaution, all manipulations were carried out under purified Ar-atmosphere in a glovebox with moisture levels <0.1 ppm.

The crystal structure of **1** was determined by single crystal X-ray diffraction.¹⁰ The crystal structure, as shown in Figure 1, features infinite chains of $[\text{NiSi}_3]^{4-}$ separated by Ba atoms. The chains consist of equilateral Si₃ triangles stacked in an eclipsed manner, forming columns of face-shared Si₆ trigonal prisms. Ni and Ba atoms form nominal “Ba₂Ni” layers, with Ni located at the centers of the Si trigonal prisms. Ba atoms cap rectangular faces of the trigonal prisms formed by eclipsed Si₃ triangles, essentially isolating the [NiSi₃] chains. There are two independent [NiSi₃]⁴⁻ chains that run parallel to the *c*-axis. One chain passes through the origin with Si–Si and Ni–Si distances of 2.454(12) and 2.426(4) Å, respectively. A second chain lies along [$1/3, 1/3, z$] with Si–Si and Ni–Si distances of 2.438(9) and 2.420(3) Å, respectively. The observed Ni–Si and Si–Si distances compare favorably to the Pauling single bond distances of (Ni–Si) 2.400 Å and (Si–Si) 2.354 Å and those found in planar cyclic Si π -systems.^{11,14} The relatively longer Si–Si distances agree with the trend observed in the C–C bonds of η^3 -cyclopropenyl–metal complexes.¹⁵

(10) Crystal Structure data for **1**: $M_r = 417.66$, hexagonal, space group P-62m (no. 189), $a = 11.392(5)$, $c = 3.938(3)$ Å, $V = 442.6(4)$ Å³, $Z = 3$, $\rho = 4.701$ g cm⁻³, $\mu = 16.810$ mm⁻¹, $\lambda = 0.71073$ Å (Mo K α), $2\theta_{\text{max}} = 56.54$; of 1261 total reflections, 411 were independent and 396 were observed ($I > 2\sigma(I)$); 23 total variables; final R indices $R1 = 0.0502$, $wR2 = 0.1201$, $\text{GOF} = 1.13$ ($I > 2\sigma(I)$) and $R1 = 0.0522$, $wR2 = 0.1217$, $\text{GOF} = 1.12$ (all data). The analysis, using a Siemens SMART diffractometer equipped with a CCD detector, was carried out at 25 °C. Empirical absorption correction was applied on a hemisphere of data, and redundant reflections were averaged. The structure was solved by direct methods and refined by full-matrix least-squares calculations. A final Fourier difference map was essentially featureless. All calculations were made with SHELXTL crystallographic software.

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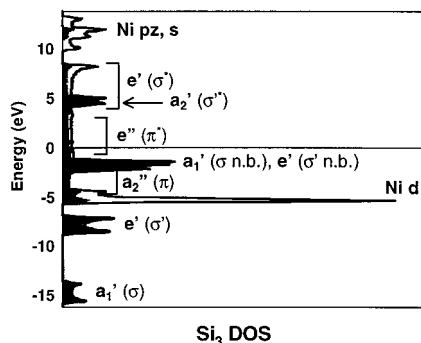


Figure 2. Total density of states of $[\text{NiSi}_3]^{4-}$ in Ba_2NiSi_3 . The Si_3 projection is shaded black, and its bands are labeled accordingly. Ni p_x and p_y bands are not shown. The Fermi level (E_F) is set to 0 eV.

The Ni-centered trigonal prismatic silicide chains in the unique crystal structure of compound **1** are similar to chains found in NbSe_3 that reportedly exhibit novel charge density wave (CDW) behavior.¹² However, significant Se–Se bonding between Se atoms of neighboring chains was observed in NbSe_3 . A closer structural relative of **1** is found in the oligomeric $[\text{ZnGe}_8]^{6-}$ cluster in Cs_6ZnGe_8 , wherein Zn atoms occupy trigonal prismatic sites formed by the eclipsed condensation of two Ge_4 pyramidal clusters.¹³

The Si_3 rings are notable features of the crystal structure. There have been reports of solid-state ring structures for silicon that are mainly derived from six-member benzene-like units.¹⁴ Detailed investigations of these electron-deficient silicides and germanides indicate the existence of cyclic tetrelide π -systems that were characterized as having partially filled π^* states.^{14,15} It is tempting to associate the structure to a Zintl electronic scheme as $(\text{Ba}^{2+})_2\text{Ni}^{2+}[\text{Si}_3]^{6-}$. However, the identical electronegativities of Ni and Si dispute this simple assignment. It is more appropriate to depict the infinite chain as a one-dimensional $[\text{NiSi}_3]^{4-}$ anion. This leads us to liken it to an infinitely stacked face-to-face metallocene polymer.¹⁶ Transition metal sandwich complexes with unsaturated cyclic P_3 and As_3 ligands are known and characterized as having metallocene-like interactions.¹⁷ To our knowledge, metal complexes or polymers with cyclic η^3 - Si_3 π -donor ligands have not yet been reported.

To understand the bonding in the $[\text{NiSi}_3]^{4-}$ chain, one-dimensional band structure calculations were performed using extended-Hückel theory.¹⁸ The calculated density of states (DOS), as shown in Figure 2, shows that there are no gaps near the Fermi level (E_F). The Ni-d bands lie above the Si s-bands and below E_F . The relevant d-bands, a_1' (d_{z^2}) and e'' (d_{xz} and d_{yz}), represent “molecular” bonding combinations between Ni and the Si_3 ligands. The occupied Si_3 -derived p-bands (a_2'' , e' , a_1' , e'') lie above the Ni d-bands, with $a_2''(\pi)$, $e''(\pi^*)$, exhibiting large bandwidths of 3 and 4.5 eV, respectively. The rest of the Si_3 occupied p-bands exhibit weak dispersions.

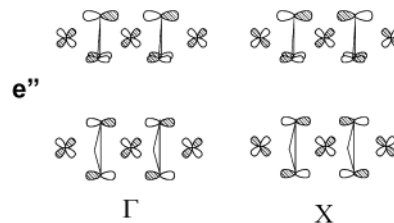
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The most significant Ni– Si_3 interactions are manifested in the $a_2''(\pi)$ and $e''(\pi^*)$ bands. At $k = 0$ (Γ), $a_2''(\pi)$ is nonbonding between Ni p_z orbital and the π -states of Si_3 , and transforms to a bonding combination at $k = \pi/2a$ (X) leading to the observed dispersion. The HOMO, $e''(\pi^*)$, exhibits significant mixing between the Ni (d_{xz} and d_{yz}) and Si_3 p_z orbitals. Antibonding interactions in $e''(\pi^*)$ at $k = 0$ (Γ), as shown in Scheme 1, become

Scheme 1



significantly bonding at $k = \pi/2a$ (X). The dispersion of the $a_2''(\pi)$ and $e''(\pi^*)$ bands provides an electronic rationale for the observed stability of the chain structure.¹⁸ The $e''(\pi^*)$ bands are partially filled only up to where the metal–ligand states are bonding. Fragment MO analyses at $k = 0$ (Γ) indicate the charge assignment as $[\text{Ni}^0\text{Si}_3^{4-}]$. However, Mulliken population analyses indicate charges are $[\text{Ni}^{1-}(\text{Si}_3)^{3-}]$ that suggests significant hybridization of Ni and Si_3 due to the extended nature of the chain. Possible “back-bonding” from the “electron-rich” Si_3^{4-} moiety to the metal is indicated by the significant mixing of empty Ni p_z states with filled Si_3 $a_2''(\pi)$ states. The average overlap populations for the Ni–Si and Si–Si bonds are 0.225 and 0.636, respectively. The overlap population between Si atoms of face-to-face Si_3 triangles is negligible. Hence, the interaction of the $[\text{Si}_3]$ trimer with Ni may be considered analogous to that observed in η^3 -cyclopropenyl-metal complexes, and that the $[\text{NiSi}_3]^{4-}$ chains are solid-state analogues of an eclipsed (η^3 - Si_3)Ni polymer.¹⁹ A significant implication of the existence of **1** is the promise of stabilizing new main-group solid-state cyclic π -systems, as in inorganic metallocene analogues.^{16,19}

Magnetic and resistivity measurements on pressed pellets indicate **1** to be Pauli paramagnetic and metallic over the range 10–300 K ($\rho_{298\text{K}} = 7 \times 10^{-5} \Omega/\text{cm}$). A report on the isostructural nickel germanide will be published in a forthcoming report.²⁰

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Supporting Information Available: Complete list of crystallographic data, atomic parameters, thermal parameters, relevant bond distances and angles, and band structure results for Ba_2NiSi_3 (PDF). This material is available free of charge via the Internet at <http://pubs.acs.org>.

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